TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC191AP, TC74HC191AF

4-Bit Binary Up/Down Counter

The TC74HC191A are high speed CMOS 4-BIT UP/DOWN COUNTERs fabricated with silicon gate $\rm C^2MOS$ technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

The TC74HC191A is 4-bit binary up/down counter.

They have an asynchronous load input (LOAD) which is active low

The direction of counting is determined by the level of DOWN/UP. When D/U is low, the counter counts up; when D/U is high, it counts down. Counting occurs on the positive going transition of the clock input.

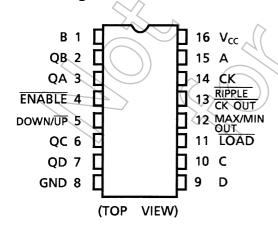
Enable input (ENABLE) and two carry inputs (RIPPLE CLOCK OUT, MAX/MIN) are provided to permit easy cascading of the counters, which facilitates easy implementation of N-bit counters without using external gates.

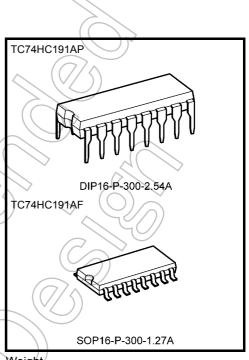
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: fmax = 48 MHz (typ.) at VCC = 5 V
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_a = 25 \text{°C}$
- High noise immunity: $V_{NIH} = V_{NIL} \neq 28\% V_{CC}$ (min)
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance; | IOH | = IOL = 4 mA (min)
- Balanced propagation delays: tpLH ≈ tpHL
- Wide operating voltage range: VCC (opr) = 2 to 6 V
- Pin and function compatible with 74LS191

Pin Assignment



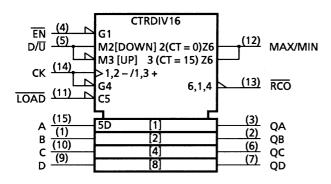


Weight

DIP16-P-300-2.54A : 1.00 g (typ.) SOP16-P-300-1.27A : 0.18 g (typ.)

Start of commercial production 1988-11

IEC Logic Symbol



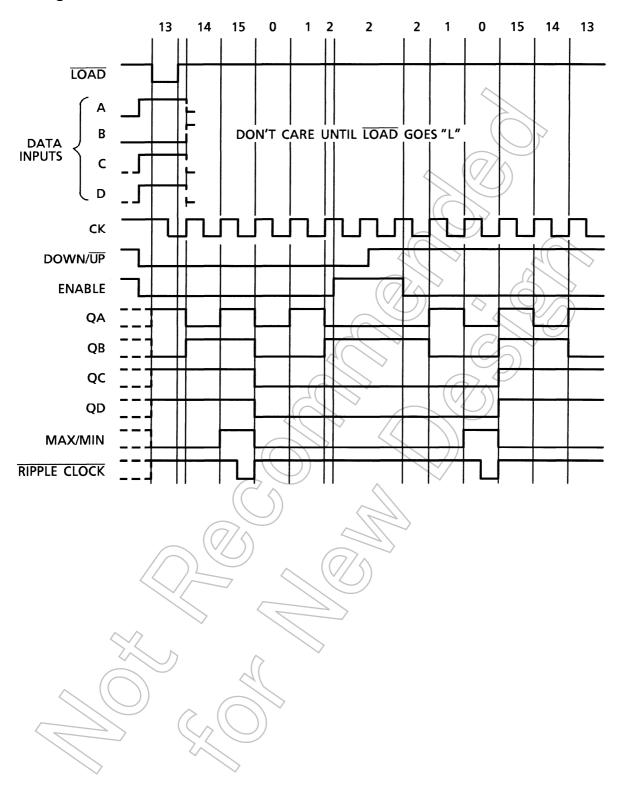
Truth Table

		Out	Function					
LOAD	ENABLE	D/Ū	CK	QA	QB	QC	QD	1 discuon
L	Х	Х	Х	а	b	С	d	Preset Data
Н	L	L			Up C	Up Count		
Н	L	Н			Down	Down Count		
Н	Н	Х			No C	No Count		
Н	Х	Х	\rightarrow		No C	hange		No Count

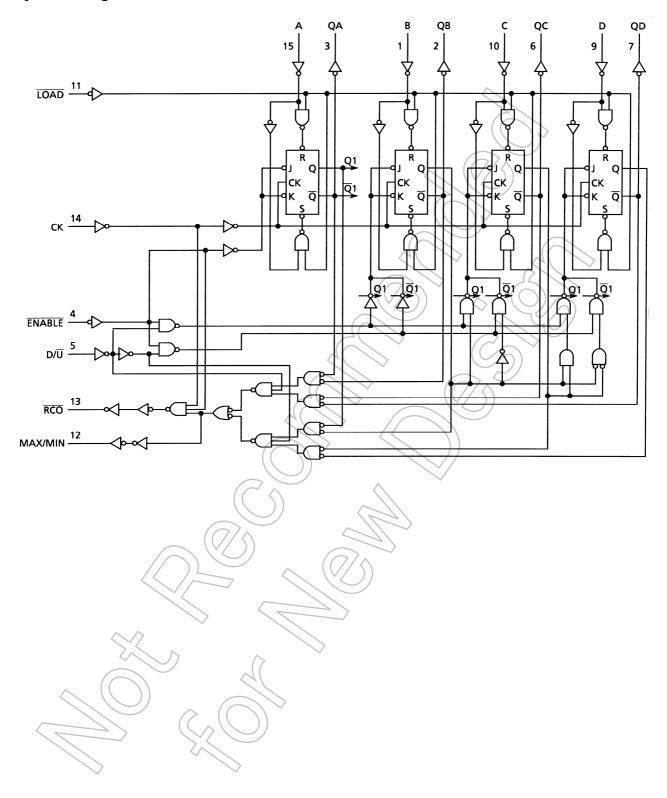
X: Don't care

a to d: Inputs level of A to D

Timing Chart



System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	–0.5 to 7	V
DC input voltage	V _{IN}	-0.5 to V _{CC} + 0.5	V
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
Input diode current	lıK	±20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±50	_mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C shall be applied until 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	VCC	2 to 6	V
Input voltage	$//\sqrt{\hat{v}_{jN}}$	0 to V _C C	٧
Output voltage	V _{OUT}	0 to V _{CC}	٧
Operating temperature	Topr	-40 to 85	°C
		0 to 1000 (V _{CC} = 2.0 V)	
Input rise and fall time	t _r , t _f	0 to 500 (V _{CC} = 4.5 V)	ns
		0 to 400 (V _{CC} = 6.0 V)	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

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Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta –40 to	Unit	
				V _{CC} (V)	Min	Тур.	Max	Min	Max	
				2.0	1.50	_ `	17	1.50	_	
High-level input voltage	V_{IH}		_	4.5	3.15	_		3.15	_	V
l				6.0	4.20			4.20	_	
				2.0	_	+0	0.50	_	0.50	
Low-level input voltage	V_{IL}		_	4.5	-	7/	1.35	_	1.35	V
				6.0	-(7	1.80	_	1.80	
	V _{ОН}	V _{IN} = V _{IH} or V _{IL}		2.0	1.9	2.0	_	1.9		
			$I_{OH} = -20 \mu A$	4.5	4.4	4.5	_	4.4		
High-level output voltage				6.0	5.9	6.0	/	5.9	\searrow	V
			$I_{OH} = -4 \text{ mA}$	4.5	4.18	4.31	6	4.13	> —	
			$I_{OH} = -5.2 \text{ mA}$	6.0	5.68	5.80	(5.63) —	
	V _{OL}			2.0	_	0.0	0.1		0.1	
			I _{OL} = 20 μA	4.5	_	0.0	0.1	~ —	0.1	
Low-level output voltage		V _{IN} = V _{IH} or V _{IL}		6.0	_	0.0	0.1/	_	0.1	V
			$I_{OL} = 4 \text{ mA}$	4.5	_	0.17 <	0.26	_	0.33	
			I _{OL} = 5.2 mA	6.0		0.18	0.26	_	0.33	
Input leakage current	I _{IN}	V _{IN} = V _{CC} or	GND	6.0	_		±0.1	_	±1.0	μА
Quiescent supply current	Icc	V _{IN} = V _{CC} or	GND	6.0		/	4.0		40.0	μА



Timing Requirements (input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40 to 85°C	Unit
			V _{CC} (V)	Тур.	Limit	Limit	
Minimum pulse width	t		2.0	_	100	125	
(CK)	tw (H)	_	4.5 <	<u> </u>	20	25	ns
(OR)	t _{W (L)}		6.0		17	21	
Minimum pulse width			2.0	(F)	75	95	
(LOAD)	t _{W (L)}	_	4.5	,>,	15	19	ns
(LOND)		<	6.0	())	13	16	
Minimum set-up time			2.0		150	190	
(ENABLE, D/Ū)	ts	_	4.5	· —	30	38	ns
(LIVIBLE, BIO)		6	6.0	_	26	33	
Minimum set-up time		4	2.0	_	50	65	
(DATA-LOAD)	ts	-	4.5		10	13	ns
(=			6.0	-(()9	11	
Minimum hold time			2.0	(4)	(0)	/ 0	
(ENABLE, D/Ū)	t _h	2	4.5	7	>0	0	ns
, -,		4()	6.0	<u>/)</u>	0	0	
Minimum hold time			2.0		0	0	
(DATA-LOAD)	t _h		4.5) —	0	0	ns
,			6.0	_	0	0	
			2.0	_	50	65	
Minimum removal time	t _{rem}		4.5	_	10	13	ns
			6.0	_	9	11	
			2.0	_	5	4	
Clock frequency			4.5	_	25	20	MHz
	$((// \le)$		6.0	_	29	24	



AC Characteristics (C_L = 15 pF, V_{CC} = 5 V, Ta = 25°C, input: t_r = t_f = 6 ns)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output transition time	t _{TLH}	_	_	4	8	ns
	t _{THL}			·	,	
Propagation delay time	t _{pLH}	<		18	31	ns
(CK-Q)	t _{pHL}	_		10	31	113
Propagation delay time	t _{pLH}	_		10	20	ns
(CK-RCO)	t _{pHL}				20	113
Propagation delay time	t _{pLH}			23	42	ns
(CK-MAX/MIN)	t _{pHL}			20	72	113
Propagation delay time	t _{pLH}		>	21	35	ns
(LOAD -Q)	t _{pHL}			21	33	113
Propagation delay time	t _{pLH}	4(>>		17	30	ns
(DATA-Q)	t _{pHL}			2	. 30	113
Propagation delay time	t _{pLH}	((//5) ~ ~)11	√ 17	ns
(ENABLE - RCO)	t _{pHL}) ''	113
Propagation delay time	t _{pLH}			17	31	ns
$(D/\overline{U} - \overline{RCO})$	t _{pHL}	4()		V 17	31	115
Propagation delay time	t _{pLH}			15	27	ns
$(D/\overline{U}$ -MAX/MIN)	t _{pHL}) _	15	21	115
Maximum clock frequency	f _{max} <		27	48	_	MHz

AC Characteristics ($C_L = 50 \text{ pF}$, input: $t_r = t_f = 6 \text{ ns}$)

Characteristics Symbo		Test Condition	Ta = 25°C			Ta = -40 to 85°C		Unit	
			V _{CC} (V)	Min	Тур.	Max	Min	Max	
	4		2.0	_	30	75	_	95	
Output transition time	t _{TLH}	_	4.5	_	8 〈	15	_	19	ns
	t _{THL}		6.0	_	7	13	_	16	
Propagation delay	t _{pLH}		2.0		88	180	7	225	
time	t _{pHL}	_	4.5	_	22	36	/ —	45	ns
(CK-Q)	PITE		6.0	\prec	19	31	_	38	
Propagation delay time	t _{pLH}		2.0	- 2	52	120	_	150	
(CK-RCO)	t _{pHL}	_	4.5	-(1	13	24	_	30	ns
(OK-NOO)			6.0		11	20		26	
Propagation delay time	t _{pLH}		2.0 4.5	1/	108 27	240 48	12	300 60	20
(CK-MAX/MIN)	t _{pHL}	_	6.0		23	41		> 50 51	ns
Propagation delay		/	2.0	2	100	205	(4)	255	
time	t _{pLH}	_	4.5	_	25	41	50	51	ns
(LOAD -Q)	t _{pHL}	40	6.0	_	22	35	_	43	
Propagation delay	t _{pLH}		2.0	_	84	175	_	220	
time	t _{pHL}	-2(4.5	_	21	35	_	44	ns
(DATA-Q)	\$PITE	4()	6.0		18	30	_	37	
Propagation delay time	t _{pLH}		2.0) 56	105	_	130	
(ENABLE - RCO)	t _{pHL}		4.5 6.0		/14 12	21 18		26 22	ns
			2.0		84	180		225	
Propagation delay time	t _{pLH}		4.5	\ —	21	36	_	45	ns
(D/ \overline{U} - \overline{RCO})	t _{pHL}	7/6	6.0	_	18	31	_	38	
Propagation delay			2.0	_	72	160	_	200	
time	t _{pLH}		4.5	_	18	32	_	40	ns
(D/ Ū -MAX/MIN)	tрнĽ		6.0	_	15	27	_	34	
Mandanian electe & A			2.0	5	11	_	4	_	
Maximum clock frequency	f _{max}		4.5	25	44	_	20	_	MHz
	\sim		6.0	29	52	_	24	_	
Input capacitance	C _{IN}	-		_	5	10	_	10	pF
Power dissipation capacitance	C _{PD} (Note)			_	101	_	_	_	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

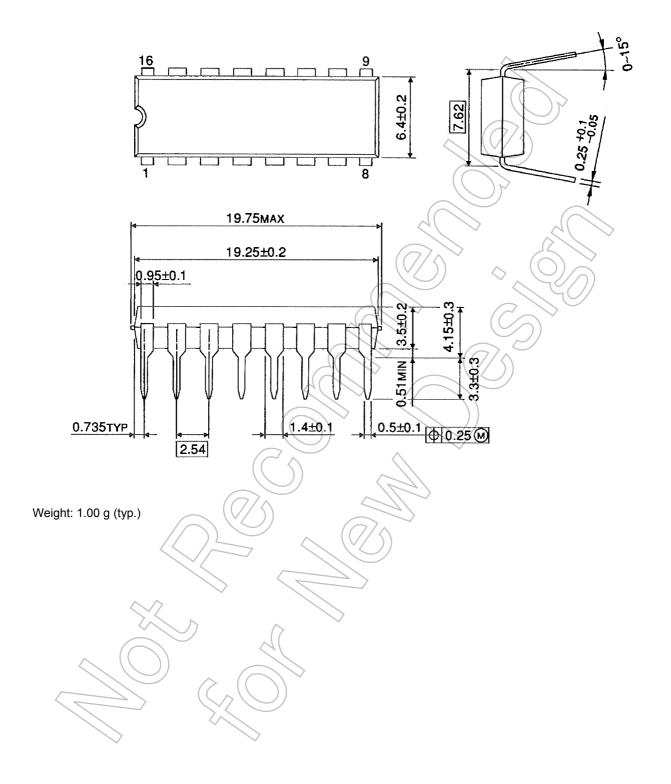
Average operating current can be obtained by the equation:

 I_{CC} (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

Package Dimensions

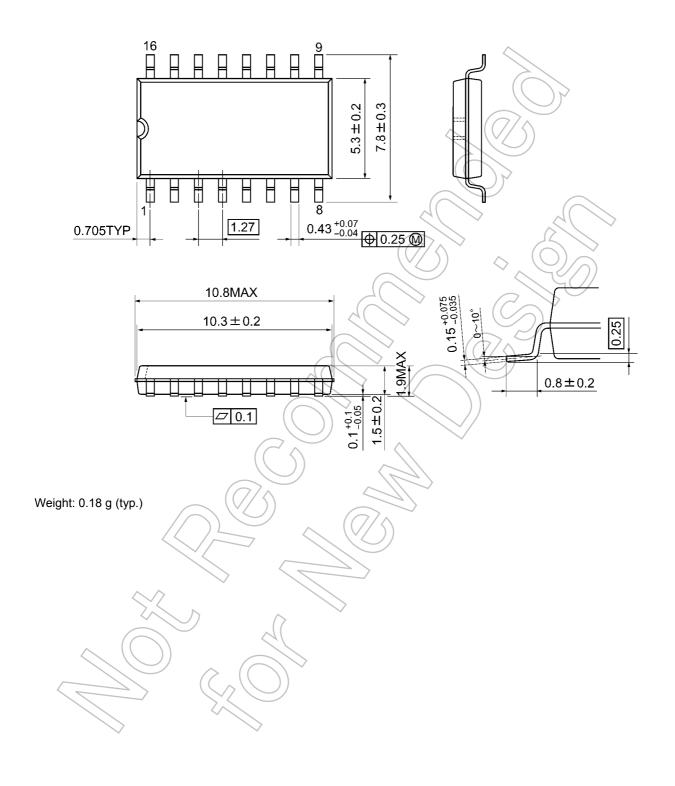
TOSHIBA

DIP16-P-300-2.54A Unit: mm



Package Dimensions

SOP16-P-300-1.27A Unit: mm



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